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Kind regards,

Team Nexperia



BAT760

Medium power Schottky barrier single diode

Rev. 03 — 17 October 2008

Product data sheet

1. Product profile

1.1 General description

Planar medium power Schottky barrier single diode with an integrated guard ring for stress protection, encapsulated in a SOD323 (SC-76) very small Surface-Mounted Device SMD plastic package.

1.2 Features

- Ultra high-speed switching
- Very low forward voltage
- Guard-ring protected
- Very small SMD plastic package

1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_R	reverse voltage		-	-	20	V
I _F	forward current		-	-	1	Α
V_{F}	forward voltage	I _F = 1 A	<u>[1]</u> _	480	550	mV

[1] Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02.$



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2. Pinning information

Table 2. Pinning

Description	Simplified outline	Graphic symbol
cathode	[1]	
anode	1 2	1 - 2
		sym001
	Description cathode	Description Simplified outline cathode [1]

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BAT760	SC-76	plastic surface-mounted package; 2 leads	SOD323

4. Marking

Table 4. Marking codes

Type number	Marking code
BAT760	A4

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{R}	reverse voltage		-	20	V
I _F	forward current		-	1	Α
I _{FSM}	non-repetitive peak forward current	t _p = 8.3 ms; half-sine wave; JEDEC method	-	5	A
T_j	junction temperature		-	125	°C
T_{amb}	ambient temperature		-65	+125	°C
T _{stg}	storage temperature		-65	+150	°C

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Thermal characteristics

Thermal characteristics Table 6.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-a)}}$	thermal resistance from	in free air				
	junction to ambient		[1]	-	220	K/W
			[2] _	-	180	K/W

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for cathode $10 \times 10 \text{ mm}^2$.

7. **Characteristics**

Product data sheet

Characteristics

T_{amb} = 25 °C unless otherwise specified.

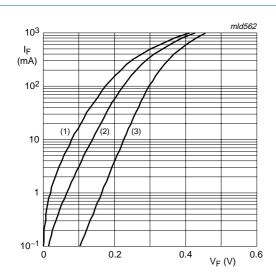
		•				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage		<u>[1]</u>			
		I _F = 10 mA	-	240	270	mV
		$I_F = 100 \text{ mA}$	-	300	350	mV
		I _F = 1 A	-	480	550	mV
I _R	reverse current		<u>[1]</u>			
		$V_R = 5 V$	-	5	10	μΑ
		$V_R = 8 V$	-	7	20	μΑ
		V _R = 15 V	-	10	50	μΑ
C_d	diode capacitance	$V_R = 5 V$; $f = 1 MHz$	-	19	25	pF

^[1] Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02.$

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode $40 \times 40 \text{ mm}^2$.

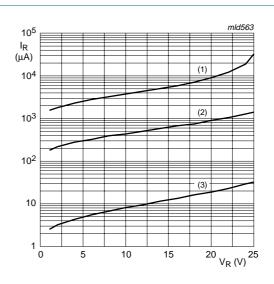
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- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$

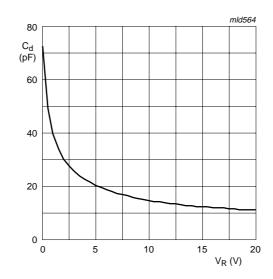
Fig 1. Forward current as a function of forward voltage; typical values



- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values

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f = 1 MHz; T_{amb} = 25 °C

Product data sheet

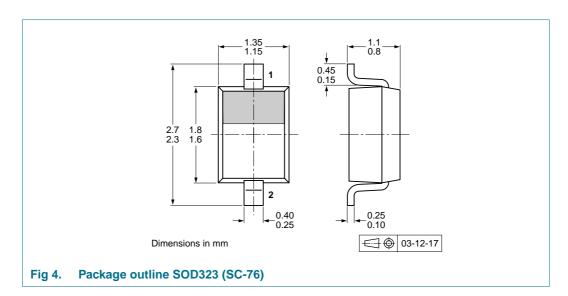
Diode capacitance as a function of reverse voltage; typical values Fig 3.

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Package outline 8.



Packing information 9.

Product data sheet

Table 8. **Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

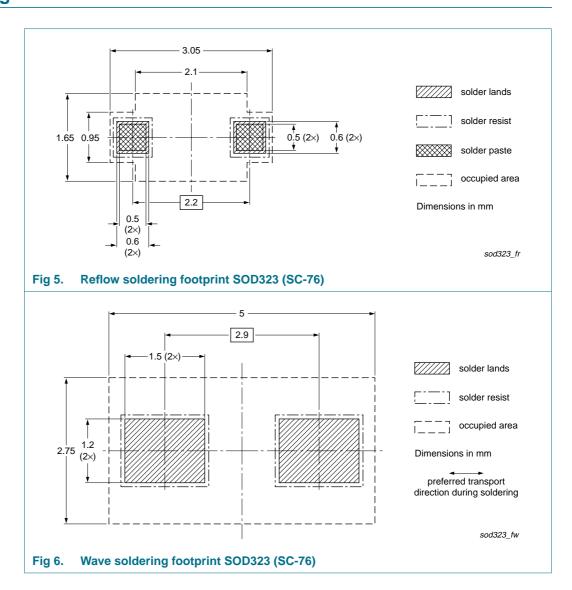
Type number	Package	Description	Packing quantity	
			3000	10000
BAT760	SOD323	4 mm pitch, 8 mm tape and reel	-115	-135

^[1] For further information and the availability of packing methods, see Section 13.

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10. Soldering



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11. Revision history

Table 9. **Revision history**

Product data sheet

BAT760_3 20081017 Product data sheet - BAT760_2 Modifications: The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. Table 1 "Quick reference data": added Figure 4: superseded by minimized package outline drawing Section 9 "Packing information": added Section 10 "Soldering": added Section 12 "Legal information": updated BAT760_2 20040126 Product specification - BAT760_1 BAT760_1 20010312 Product specification							
Modifications: • The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. • Legal texts have been adapted to the new company name where appropriate. • Table 1 "Quick reference data": added • Figure 4: superseded by minimized package outline drawing • Section 9 "Packing information": added • Section 10 "Soldering": added • Section 12 "Legal information": updated BAT760_2 20040126 Product specification - BAT760_1	Document ID	Release date	Data sheet status	Change notice	Supersedes		
guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. Table 1 "Quick reference data": added Figure 4: superseded by minimized package outline drawing Section 9 "Packing information": added Section 10 "Soldering": added Section 12 "Legal information": updated BAT760_2 BAT760_1	BAT760_3	20081017	Product data sheet	-	BAT760_2		
• Table 1 "Quick reference data": added • Figure 4: superseded by minimized package outline drawing • Section 9 "Packing information": added • Section 10 "Soldering": added • Section 12 "Legal information": updated BAT760_2 20040126 Product specification - BAT760_1	Modifications:			redesigned to comply w	ith the new identity		
• Figure 4: superseded by minimized package outline drawing • Section 9 "Packing information": added • Section 10 "Soldering": added • Section 12 "Legal information": updated BAT760_2 20040126 Product specification - BAT760_1		 Legal texts have 	e been adapted to the n	ew company name whe	re appropriate.		
Section 9 "Packing information": added Section 10 "Soldering": added Section 12 "Legal information": updated BAT760_2 20040126 Product specification - BAT760_1							
Section 10 "Soldering": added Section 12 "Legal information": updated BAT760_2 20040126 Product specification - BAT760_1							
Section 12 "Legal information": updated BAT760_2 20040126 Product specification - BAT760_1		 Section 9 "Pack 	king information": added				
BAT760_2 20040126 Product specification - BAT760_1		 Section 10 "Sol 	dering": added				
<u> </u>		 Section 12 "Leg 	gal information": updated	I			
BAT760_1 20010312 Product specification	BAT760_2	20040126	Product specification	-	BAT760_1		
	BAT760_1	20010312	Product specification	-	-		

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12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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